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FDD5N50FTM_WS N-Channel UniFETTM FRFET[®] MOSFET 500 V, 3.5 A, 1.55 Ω

Features

- R_{DS(on)} = 1.25Ω (Typ.) @ V_{GS} = 10 V, I_D = 1.75 A
- Low Gate Charge (Typ. 11 nC)
- Low C_{rss} (Typ. 5 pF)
- · Fast Switching
- 100% Avalanche Tested
- · Improved dv/dt Capability
- RoHS Compliant

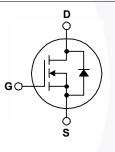
Applications

- LCD/LED/PDP TV
- Lighting
- Uninterruptible Power Supply
- AC-DC Power Supply

Description

UniFETTM MOSFET is Fairchild Semiconductor's high voltage MOSFET family based on planar stripe and DMOS technology. This MOSFET is tailored to reduce on-state resistance, and to provide better switching performance and higher avalanche energy strength. The body diode's reverse recovery performance of UniFET FRFET[®] MOSFET has been enhanced by lifetime control. Its trr is less than 100nsec and the reverse dv/dt immunity is 15V/ns while normal planar MOSFETs have over 200nsec and 4.5V/nsec respectively. Therefore, it can remove additional component and improve system reliability in certain applications in which the performance of MOSFET's body diode is significant. This device family is suitable for switching power converter applications such as power factor correction (PFC), flat





MOSFET Maximum Ratings T_C = 25°C unless otherwise noted.

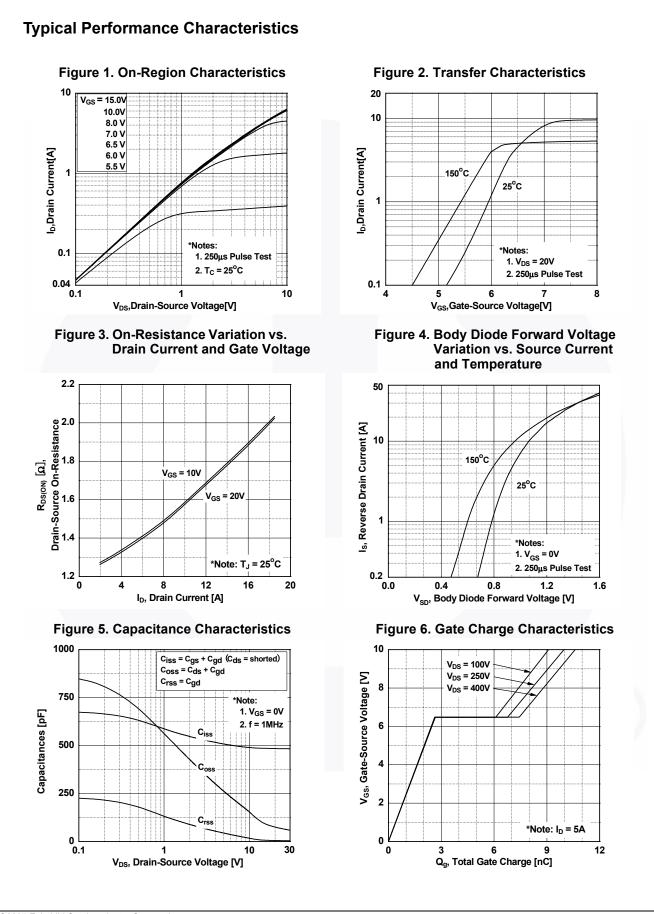
Symbol		Ratings	Units			
V _{DSS}	Drain to Source Voltage	500	V			
V _{GSS}	Gate to Source Voltage			±30	V	
I _D	Drain Current	- Continuous (T _C = 25 ^o C)		3.5	Α	
		- Continuous (T _C = 100 ^o C)		2.1	- A	
DM	Drain Current	- Pulsed	(Note 1)	14	A	
E _{AS}	Single Pulsed Avalanche E	(Note 2)	257	mJ		
AR	Avalanche Current	(Note 1)	3.5	A		
E _{AR}	Repetitive Avalanche Energ	(Note 1)	4	mJ		
dv/dt	Peak Diode Recovery dv/dt	(Note 3)	4.5	V/ns		
P _D	Devuer Dissingtion	(T _C = 25°C)		40	W	
	Power Dissipation	- Derate Above 25 ^o C		0.3	W/ºC	
T _J , T _{STG}	Operating and Storage Temperature Range			-55 to +150	°C	
TL	Maximum Lead Temperature for Soldering, 1/8" from Case for 5 Seconds			300	°C	

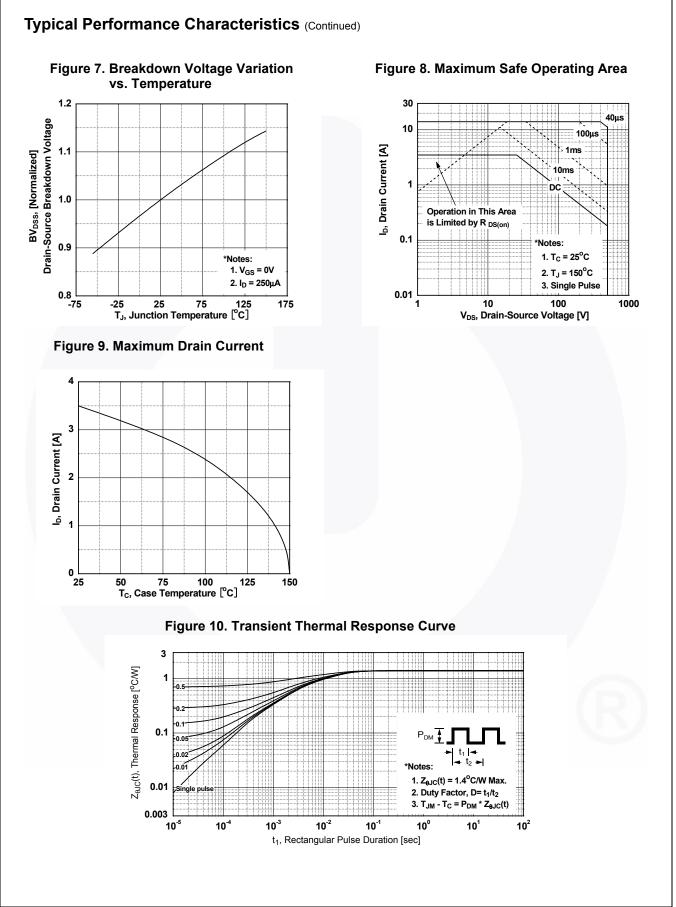
Thermal Characteristics

Symbol	Parameter	Ratings	Units
$R_{ extsf{ heta}JC}$	Thermal Resistance, Junction to Case, Max.	1.4	°C/W
R_{\thetaJA}	Thermal Resistance, Junction to Ambient, Max.	110	C/W

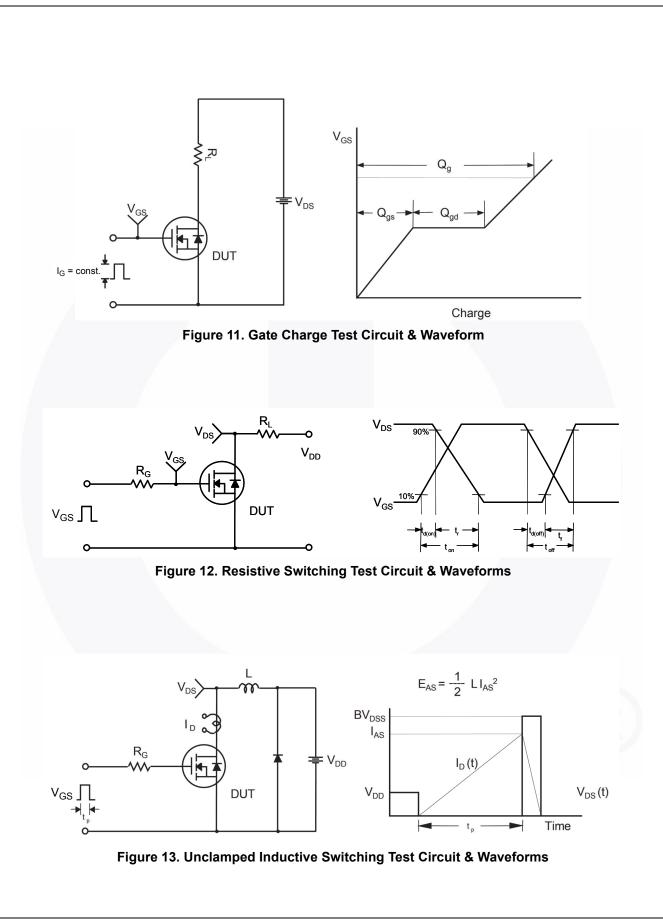
•		Top Mark Pack		<u> </u>		Tape Width16 mm		Quantity 2500 units	
		D-PAK							
Electrica	l Chara	cteristics T _C = 25°	C unless oth	nerwise noted.					
Symbol	Parameter			Test Conditions		Min.	Тур.	Max.	Units
Off Charac	teristics								
BV _{DSS}	Drain to Source Breakdown Voltage		ie Ir	I _D = 250 μA, V _{GS} = 0 V, T _J = 25 ^o C		500	-	-	V
$\frac{\Delta BV_{DSS}}{\Delta T_{,l}}$	Breakdown Voltage Temperature Coefficient			$I_D = 250 \ \mu\text{A}, \text{ Referenced to } 25^{\circ}\text{C}$		-	0.6	-	V/ºC
			V	$V_{DS} = 500 V, V_{GS} = 0 V$ $V_{DS} = 400 V, T_{C} = 125^{\circ}C$		-	-	10	
I _{DSS}	Zero Gate	e Voltage Drain Current				-	-	100	μA
I _{GSS}	Gate to Body Leakage Current			$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0 \text{ V}$		-	-	±100	nA
On Charac	toristics								
	-	ashald Valtaga	N	(-)() - 250(3.0	-	5.0	V
V _{GS(th)}		eshold Voltage iin to Source On Resista		$V_{GS} = V_{DS}, I_D = 250 \mu A$ $V_{GS} = 10 V, I_D = 1.75 A$		3.0	- 1.25	1.55	ν Ω
R _{DS(on)}		Transconductance		$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 1.75 \text{ A}$ $V_{DS} = 20 \text{ V}, \text{ I}_{D} = 1.75 \text{ A}$			4.3	1.55	S
9fs	Torward	Transconductance	v	<u>DS - 20 V, ID - 1.70 P</u>		-	4.5		0
Dynamic C	haracter	istics							
C _{iss}	Input Cap	acitance	N	V _{DS} = 25 V, V _{GS} = 0 V f = 1 MHz		-	490	650	pF
C _{oss}		apacitance				-	66	88	pF
C _{rss}	Reverse ⁻	Fransfer Capacitance				-	5	7.5	pF
Q _{g(tot)}	Total Gate	e Charge at 10V		$\frac{V_{DS} = 400 \text{ V}, \text{ I}_{D} = 5 \text{ A},}{V_{GS} = 10 \text{ V}}$ (Note 4)		-	11	15	nC
Q _{gs}	Gate to S	ource Gate Charge				-	3	-	nC
Q _{gd}	Gate to D	rain "Miller" Charge	V			-	5	-	nC
Switching	Characte	eristics			L				
t _{d(on)}		Delay Time		V_{DD} = 250 V, I _D = 5 A R _G = 25 Ω (Note 4)		-	13	36	ns
t _r		Rise Time	v			-	22	54	ns
t _{d(off)}		Delay Time				-	28	66	ns
t _f	Turn-Off F	,				-	20	50	ns
		Charactoristics	L		I		I		
	urce Diode Characteristics			onward Current		-	-	3.5	A
l _s	Maximum Continuous Drain to Source Dio Maximum Pulsed Drain to Source Diode F							14	A
I _{SM} V _{SD}	Drain to Source Diode Forward Voltage			$V_{GS} = 0 \text{ V}, \text{ I}_{SD} = 3.5 \text{ A}$		-	-	1.5	V
t _{rr}		Recovery Time		$r_{GS} = 0 V, I_{SD} = 5 A$		-	65	-	ns
Q _{rr}		Recovery Charge		$dI_{\rm F}/dt = 100 {\rm A}/{\mu {\rm s}}$		-	0.120	-	μC
:: L = 42 mH, I_{AS} :: $I_{SD} ≤ 3.5 A, di/d$	= 3.5 A, V _{DD} = dt ≤ 200 A/μs, \	mited by maximum junction temp 50 V, $R_G = 25 \Omega$, starting $T_J = 25$ $_{DD} \le BV_{DSS}$, starting $T_J = 25^{\circ}C$. rating temperature typical charac	°C.					G	2

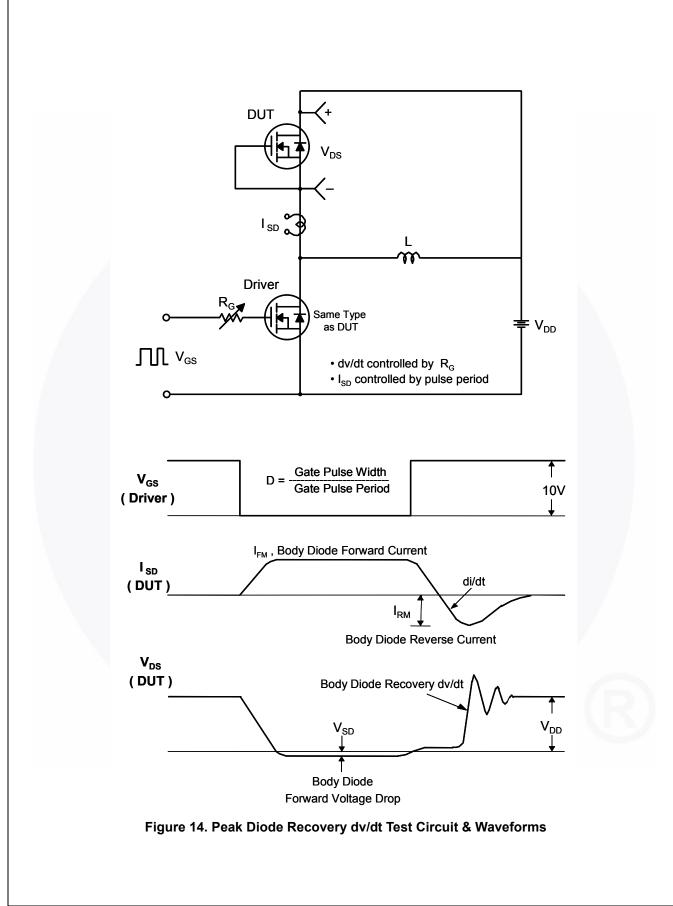
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FDD5N50FTM_WS — N-Channel UniFETTM FRFET[®] MOSFET







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